

Features

- Wide supply voltage range from 0.8V to 3.6V
- Inputs accept voltages up to 3.6V
- I_{OFF} supports partial-power-down mode
- Low static power consumption; $I_{CC}=0.5\mu A$ (Max.)
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

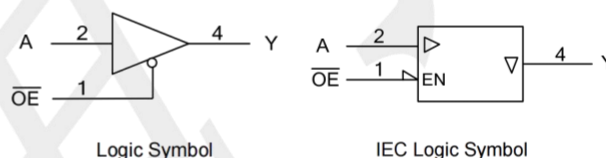
General Description

The SN74AUP1G125 is a single bus buffer/line driver with 3-state output. When the output enable ($\overline{OE}$) is high the output will be disabled. In contrast, when the $\overline{OE}$ is low, true data will pass from A input to the Y output.

Applications

- AV Receiver
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive (SSD): Client and Enterprise
- Wireless Headset, Keyboard, and Mouse

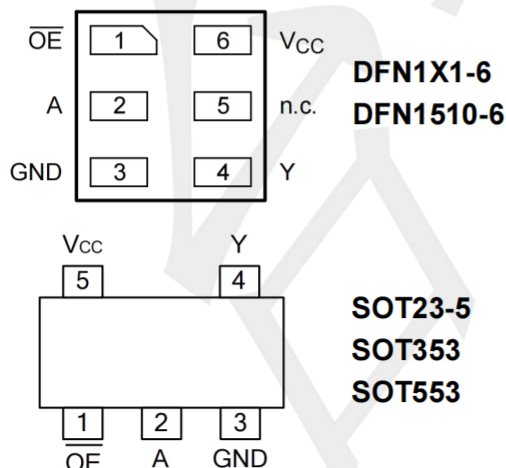
Logic Diagram



Ordering Information

ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION
SN74AUP1G125DBVR-TP	SOT23-5	Tape and Reel, 3000
SN74AUP1G125DCKR-TP	SOT353	Tape and Reel, 3000
SN74AUP1G125DRLR-TP	SOT553	Tape and Reel, 4000
SN74AUP1G125DSFR-TP	DFN1X1-6	Tape and Reel, 5000
SN74AUP1G125DRYR-TP	DFN1510-6	Tape and Reel, 5000

Pin Configuratio (TOP VIEW)



Function Table (each gate)

INPUT($\overline{OE}$)	INPUT(A)	OUTPUT(Y)
L	L	L
L	H	H
H	X	Z

H: HIGH voltage level; L: LOW voltage level;
X=don't care; Z=high-impedance OFF-state.

Absolute Maximum Ratings

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Supply Voltage	V _{CC}		-0.5 ~ +4.6	V
Input Voltage	V _{IN}		-0.5 ~ +4.6	V
Output Voltage	V _{OUT}	Output in the high or low state	-0.5 ~ +V _{CC} +0.5V	V
		Output in the power-off state	-0.5 ~ +4.6	V
V _{CC} or GND Current	I _{CC}		±50	mA
Continuous Output Current	I _{OUT}	V _{OUT} =0~V _{CC}	±20	mA
Input Clamp Current	I _{IK}	V _{IN} <0	-50	mA
Output Clamp Current	I _{OK}	V _{OUT} <0	-50	mA
Storage Temperature Range	T _{STG}		-65 ~ +150	°C
Junction to Ambient	θ _{JA}	SOT-23-5	230	°C/W
		SOT353	280	°C/W
		SOT553	250	°C/W
		DFN1X1-6	460	°C/W
		DFN1510-6	440	°C/W

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V _{CC}	Operating	0.8	--	3.6	V
Input Voltage	V _{IN}		0	--	3.6	V
Output Voltage	V _{OUT}	High or low state	0	--	V _{CC}	V
Input Transition Rise or Fall Rate	Δt/Δv	V _{CC} =0.8V ~ 3.6V	--	--	200	ns/V
Operating Temperature	T _A		-40	--	+125	°C

Electrical Characteristics (T_A=25°C ,unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-level Input Voltage	V _{IH}	V _{CC} =0.8V	0.7×V _{CC}	--	--	V
		V _{CC} =0.9V ~ 1.95V	0.65×V _{CC}	--	--	V
		V _{CC} =2.3V ~ 2.7V	1.6	--	--	V
		V _{CC} =3V ~ 3.6V	2	--	--	V
Low-level Input Voltage	V _{IL}	V _{CC} =0.8V	--	--	0.3×V _{CC}	V
		V _{CC} =1.1V ~ 1.95V	--	--	0.35×V _{CC}	V
		V _{CC} =2.3V ~ 2.7V	--	--	0.7	V
		V _{CC} =3V ~ 3.6V	--	--	0.9	V
High-Level Output Voltage	V _{OH}	V _{CC} =0.8 ~ 3.6V, I _{OH} =-20μA	V _{CC} -0.1	--	--	V
		V _{CC} =1.1V, I _{OH} =-1.1mA	0.75×V _{CC}	--	--	V
		V _{CC} =1.4V, I _{OH} =-1.7mA	1.11	--	--	V
		V _{CC} =1.65V, I _{OH} =-1.9mA	1.32	--	--	V
		V _{CC} =2.3V	I _{OH} =-2.3mA	2.05	--	V
			I _{OH} =-3.1mA	1.9	--	V
		V _{CC} =3V	I _{OH} =-2.7mA	2.72	--	V
			I _{OH} =-4mA	2.6	--	V
Low-Level Output Voltage	V _{OL}	V _{CC} =0.8 ~ 3.6V, I _{OL} =20μA	--	--	0.1	V
		V _{CC} =1.1V, I _{OL} =1.1mA	--	--	0.3×V _{CC}	V
		V _{CC} =1.4V, I _{OL} =1.7mA	--	--	0.31	V
		V _{CC} =1.65V, I _{OL} =1.9mA	--	--	0.31	V
		V _{CC} =2.3V	I _{OL} =2.3mA	--	0.31	V
			I _{OL} =3.1mA	--	0.44	V
		V _{CC} =3V	I _{OL} =2.7mA	--	0.31	V
			I _{OL} =4mA	--	0.44	V
Input Leakage Current	I _{I(LEAK)}	V _{CC} =0 ~ 3.6V, V _{IN} =GND ~ 3.6V	--	--	±0.1	μA
Power OFF Leakage Current	I _{off}	V _{CC} =0 V, V _{IN} or V _{OUT} =0 ~ 3.6V	--	--	±0.2	μA
Additional Power OFF Leakage Current	ΔI _{off}	V _{CC} =0 V~0.2V, V _{IN} or V _{OUT} =0 ~ 3.6V	--	--	±0.2	μA
Quiescent Supply Current	I _{CC}	V _{CC} =0.8 ~ 3.6V, V _{IN} =V _{CC} or GND, I _{OUT} =0	--	--	0.5	μA
Additional Quiescent Supply Current Per Input Pin	ΔI _{CC}	V _{CC} =3.3 V, V _{IN} =V _{CC} -0.6V, I _{OUT} =0	--	--	40	μA
Input Capacitance	C _I	V _{CC} =0V-3.6V, V _{IN} =V _{CC} or GND	--	1.7	--	pF
Output Capacitance	C _{OUT}	V _{CC} =0V, V _{OUT} =GND	--	1.5	--	pF

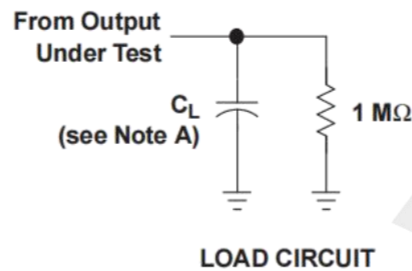
OPERATING CHARACTERISTICS (f=10MHz, TA =25°C , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C _{PD}	V _{CC} =0.8V	--	2.7	--	pF
		V _{CC} =1.2±0.1V	--	2.8	--	pF
		V _{CC} =1.5±0.1V	--	2.9	--	pF
		V _{CC} =1.8±0.15V	--	3.0	--	pF
		V _{CC} =2.5±0.2V	--	3.6	--	pF
		V _{CC} =3.3±0.3V	--	4.2	--	pF

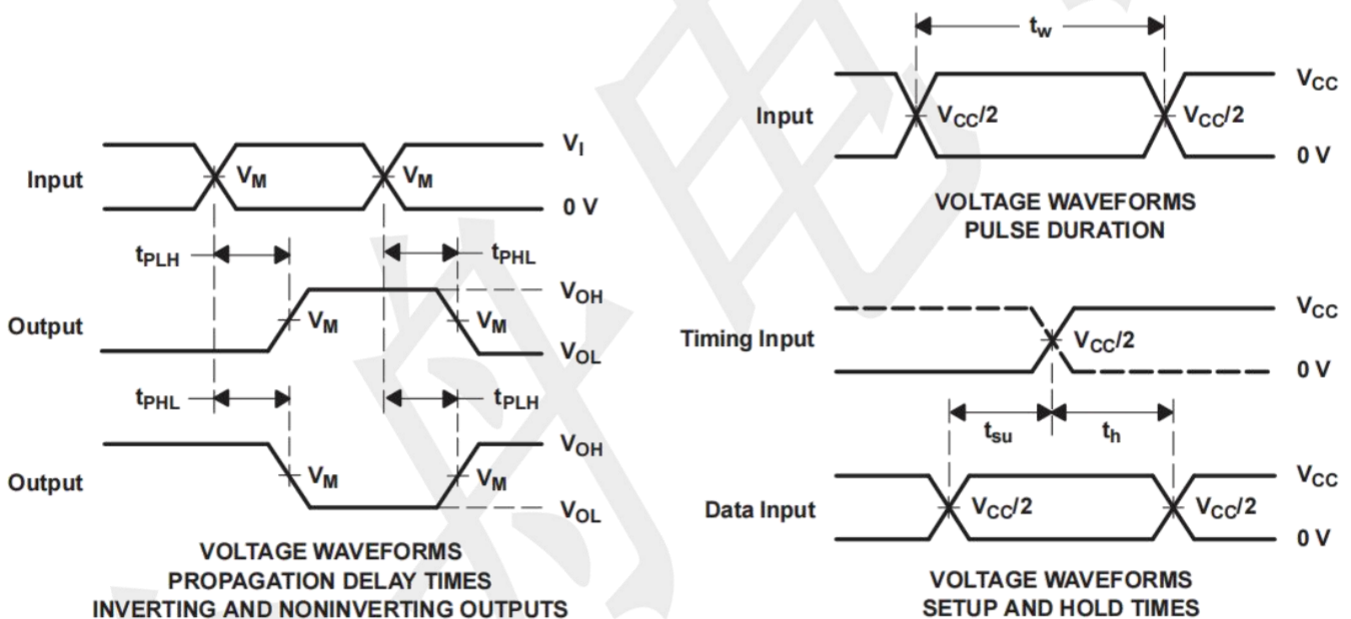
SWITCHING CHARACTERISTICS (TA =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Propagation delay from inputs (A) to output(Y)	t _{PD}	CL=5pF, RL=1MΩ	V _{CC} =0.8V	--	20.6	--	ns
			V _{CC} =1.2±0.1V	2.8	5.5	10.5	ns
			V _{CC} =1.5±0.1V	2.2	3.9	6.1	ns
			V _{CC} =1.8±0.15V	1.9	3.2	4.8	ns
			V _{CC} =2.5±0.2V	1.6	2.6	3.6	ns
			V _{CC} =3.3±0.3V	1.4	2.4	3.1	ns
		CL=10pF, RL=1MΩ	V _{CC} =0.8V	--	24.0	--	ns
			V _{CC} =1.2±0.1V	3.2	6.4	12.3	ns
			V _{CC} =1.5±0.1V	2.1	4.5	7.3	ns
			V _{CC} =1.8±0.15V	1.9	3.8	5.5	ns
			V _{CC} =2.5±0.2V	2.1	3.2	4.2	ns
			V _{CC} =3.3±0.3V	1.8	3.0	3.8	ns
		CL=15pF, RL=1MΩ	V _{CC} =0.8V	--	24.7	--	ns
			V _{CC} =1.2±0.1V	3.6	7.2	14.1	ns
			V _{CC} =1.5±0.1V	3.0	5.1	8.1	ns
			V _{CC} =1.8±0.15V	2.2	4.3	6.3	ns
			V _{CC} =2.5±0.2V	2.0	3.7	4.9	ns
			V _{CC} =3.3±0.3V	2.0	3.5	4.4	ns
		CL=30pF, RL=1MΩ	V _{CC} =0.8V	--	37.4	--	ns
			V _{CC} =1.2±0.1V	4.8	9.5	19	ns
			V _{CC} =1.5±0.1V	4.0	6.7	10.8	ns
			V _{CC} =1.8±0.15V	2.9	5.6	8.4	ns
			V _{CC} =2.5±0.2V	2.7	4.8	6.3	ns
			V _{CC} =3.3±0.3V	2.7	4.6	5.8	ns

TEST CIRCUIT AND WAVEFORMS



	$V_{CC} = 0.8 \text{ V}$	$V_{CC} = 1.2 \text{ V} \pm 0.1 \text{ V}$	$V_{CC} = 1.5 \text{ V} \pm 0.1 \text{ V}$	$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$
C_L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V_M	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
V_I	V_{CC}	V_{CC}	V_{CC}	V_{CC}	V_{CC}	V_{CC}

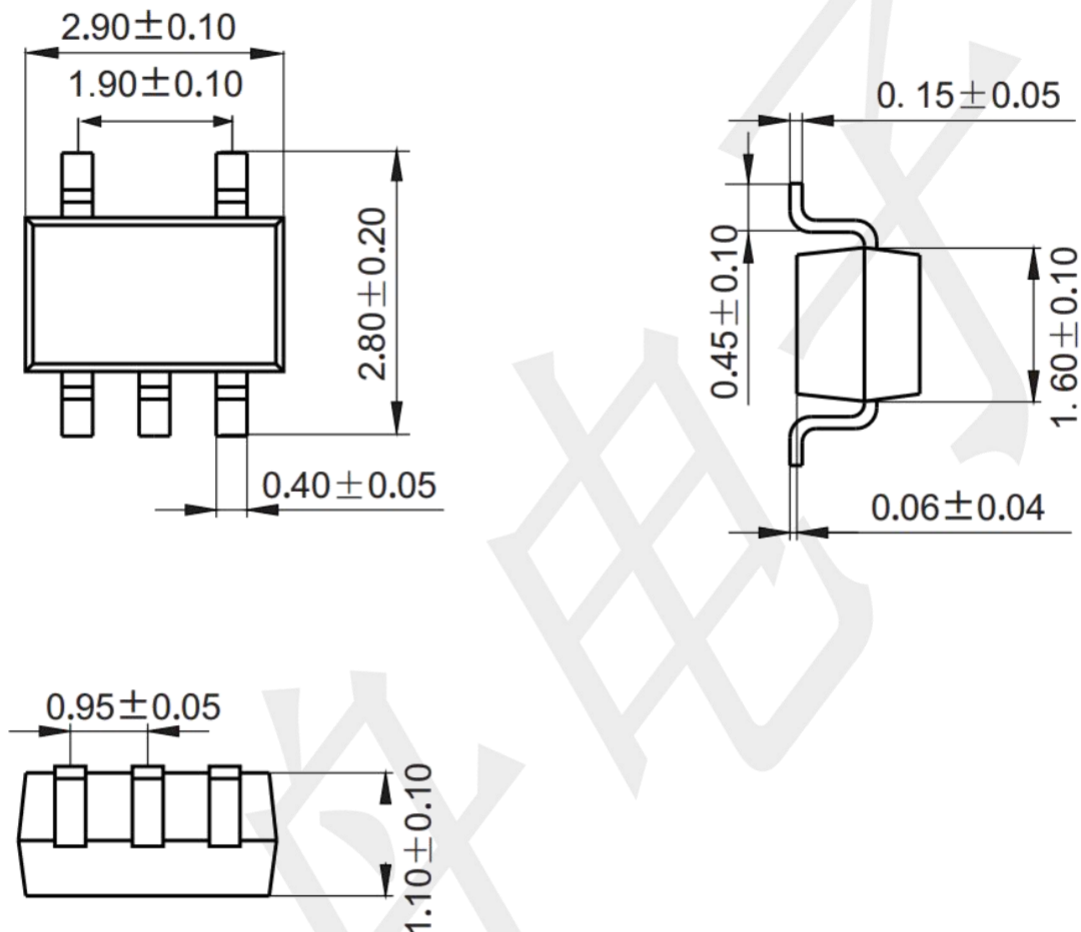


Notes:

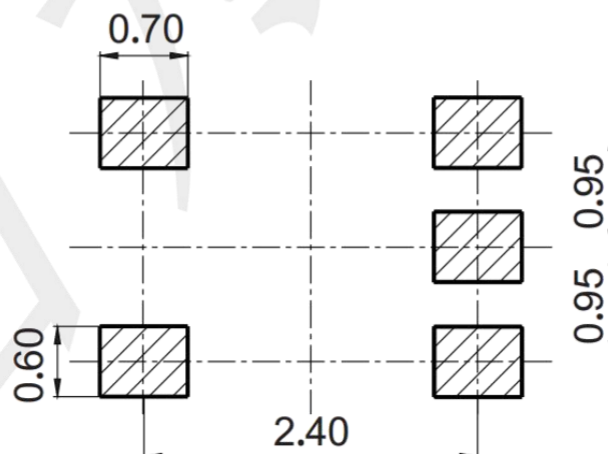
1. C_L includes probe and jig capacitance.
2. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10\text{MHz}$, $Z_O = 50\Omega$.
3. The outputs are measured one at a time, with one transition per measurement.
4. t_{PLH} and t_{PHL} are the same as t_{pd} .
5. All parameters and waveforms are not applicable to all devices

Package information (Unit: mm)

SOT23-5

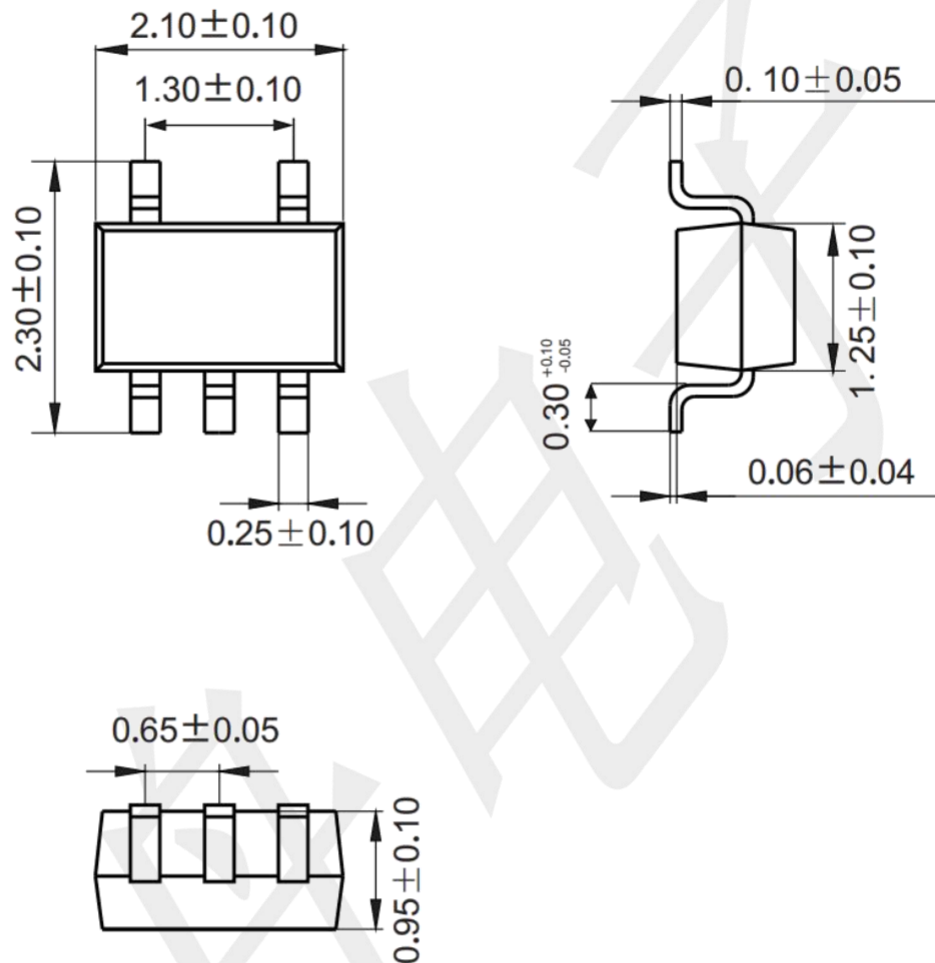


Mounting Pad Layout (unit: mm)

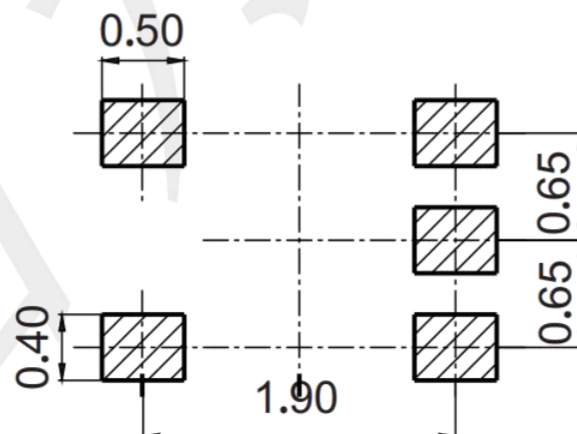


Package information (Unit: mm)

SOT353

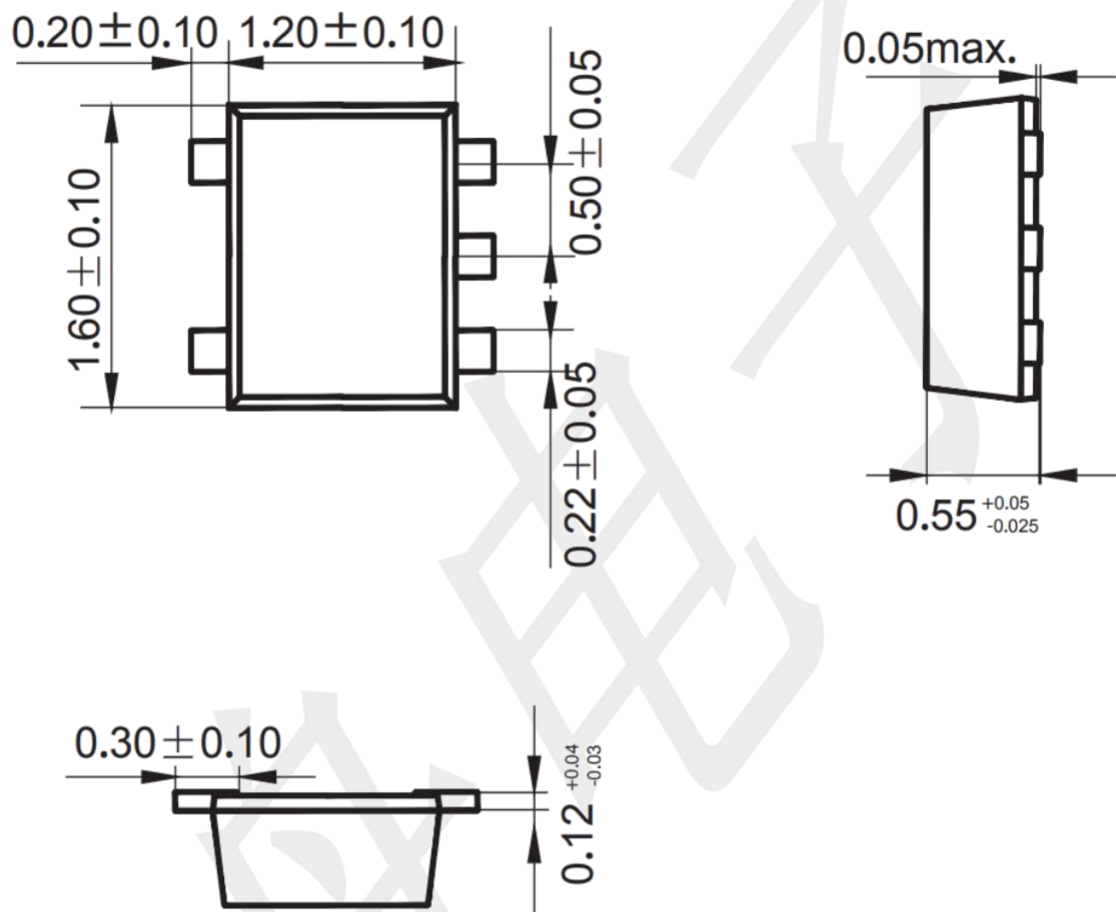


Mounting Pad Layout (unit: mm)

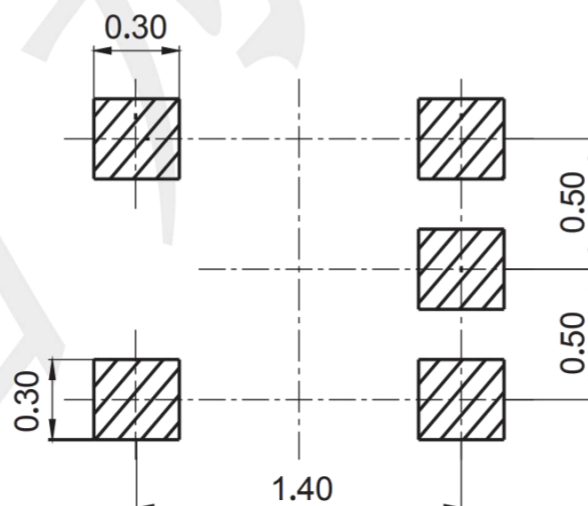


Package information (unit: mm)

SOT553

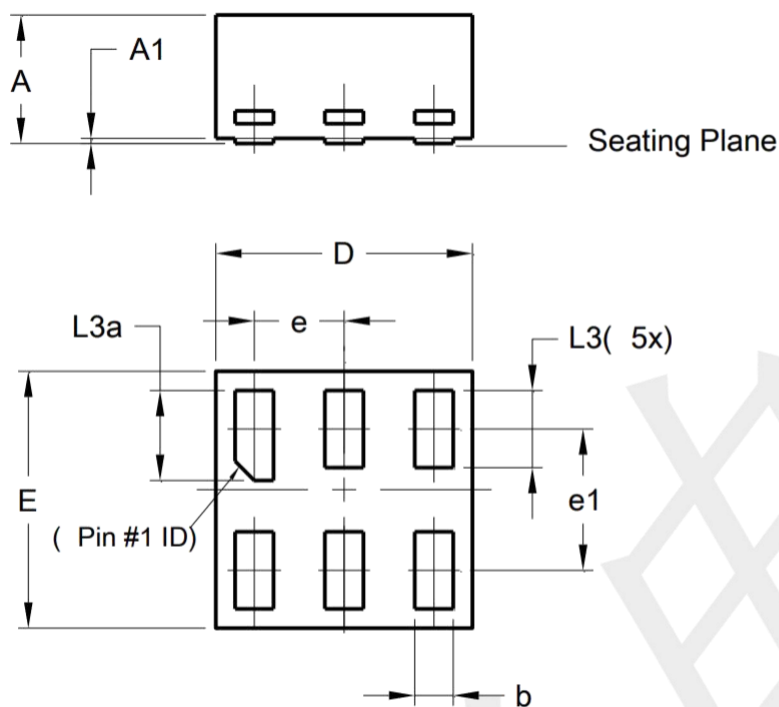


Mounting Pad Layout (unit: mm)



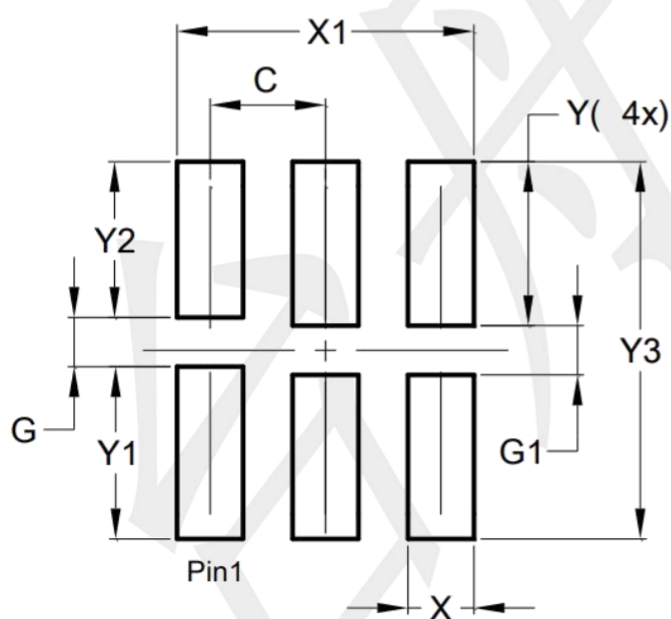
Package information (unit: mm)

DFN1X1-6



DFN1010-6 (Type B)			
Dim	Min	Max	Typ
A	-	0.50	0.39
A1	-	0.04	-
b	0.12	0.20	0.15
D	0.95	1.050	1.00
E	0.95	1.050	1.00
e	0.35 BSC		
e1	0.55 BSC		
L3	0.27	0.30	0.30
L3a	0.32	0.40	0.35
All Dimensions in mm			

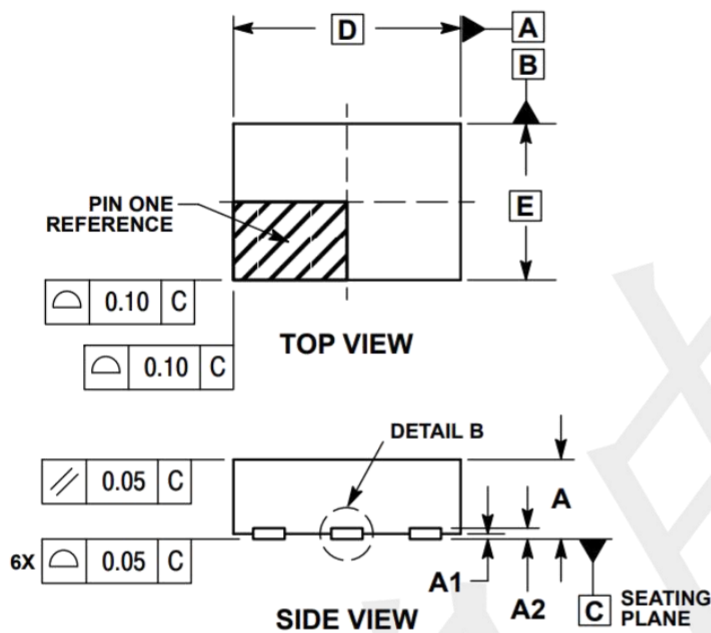
Mounting Pad Layout (unit: mm)



Dimensions	Value (in mm)
C	0.350
G	0.150
G1	0.150
X	0.200
X1	0.900
Y	0.500
Y1	0.525
Y2	0.475
Y3	1.150

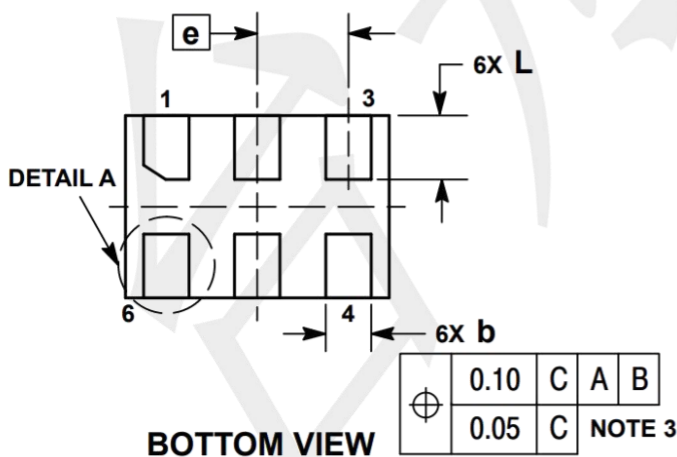
Package information (unit: mm)

DFN1510-6



DIM	MILLIMETERS	
	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A2	0.07 REF	
b	0.20	0.30
D	1.45 BSC	
E	1.00 BSC	
e	0.50 BSC	
L	0.30	0.40
L1	---	0.15

Mounting Pad Layout (unit: mm)



MOUNTING FOOTPRINT

